



Effect of polyethylene glycol and propyltrimethoxysilane on structural and optical properties of zinc oxide nanoparticles synthesized by sol–gel process

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Abstract

Zinc oxide nanoparticles (ZnO NPs) are prepared by sol–gel process, using both polyethylene glycol (PEG-400) as surfactant and propyltrimethoxysilane (PTMS) as capping agent. Surface modification is performed in situ procedure. The physical parameters such as strain and stress values are calculated via the Williamson–Hall plot (W&H) assuming a uniform deformation model (UDM) and uniform stress deformation model, and by the size and strain plot method (SSP). The results show that the crystallite size estimated from Scherrer's formula, (W&H), (UDM), (SSP) and the particle size estimated from DSL are inter-correlated, which confirm the small size and the isotropic nature of our ZnO NPs. The FTIR spectroscopy illustrates that PEG-400 and PTMS could be adsorbed at the ZnO NPs surface. The distinct emission peak in the blue band is located at 490 nm and E_2 (high) mode is situated at 436 cm^{-1} . Both results confirm the oxygen deficiency in the ZnO NPs.

Keywords Sol–gel synthesis · Zinc oxide · PEG-400 · Propyltrimethoxysilane · Nanoparticles · DRX

Introduction

Zinc oxide (ZnO) is known as an important semiconductor for its favorable properties as transparency [1], high electron mobility [2], wide band gap [3], tough room

temperature [4] and luminescence [5]. In the last few years, there has been a growing interest of the researchers, focusing on the synthesis of nanocrystalline ZnO, hence, many methods, including sol–gel [6–9]. Thereby, particle size and crystal morphology play important roles in all applications, like nanodevices for opto-electronic [10], gas sensing [11], photocatalytic activity [12]. A part of the technological meaning of zinc oxide nanoparticles (ZnO NPs), their diameters ranging from 10 to 100 nm make them good-looking from academic point of view [13].

The current paper presents a novel method to use both polyethylene glycol (PEG-400) and propyltrimethoxysilane (PTMS) as surfactant and capping agent, respectively. Because several publications have demonstrated that PEG-400 is easily adsorbed at the surface of a metal oxide and modifies the kinetics of the growing colloids. In addition, it is well known that PEG-400 dissolved in alcohol increases the viscosity. This process not only significantly shortens the reaction time for preparing ZnO, but also increases the crystallinity of the ZnO NPs. When PEG-400 is added before synthesis, the probability of electrostatic adsorption of ZnO NPs increased. It has been proposed to add silane to

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enhance the stability and to prevent ZnO agglomeration. In this case, it would be important that PTMS could protect the surface against agglomeration in the presence of PEG-400, and control their size and photoemission properties [13–17]. A perfect crystal would extend infinitely in all directions, for that reason, no crystal is perfect due to its finite size. This deviation from perfect crystallinity leads to a broadening of the diffraction peaks. In our study, we explore the possibility to have good crystallinity and small size of ZnO NPs.

Experimental procedure

Synthesis of ZnO nanoparticles

In order to synthesize ZnO NPs, the major step is the preparation of the organometallic precursor containing (0.1 M de Zn^{2+}) ($C_4H_6O_4Zn \cdot 2H_2O$ from Aldrich) in absolute ethanol, where the solution is refluxed at 80 °C, under continuous stirring and atmospheric pressure. After 2 h, the as-obtained solution is cooled and is stirred about 30 min to ensure good dispersion while adding the PEG-400. Consequently, the PTMS is added drop wise to the solution during 40 min. An aliquot of lithium oxide ($LiOH \cdot H_2O$) solution prepared in ethanol (0.25 M) is dropped to the previous solution. So, a transparent solution containing ZnO NPs quantum dot is obtained. The resulting white powder is obtained by precipitation of previous solution with hexane. The product is washed by ethanol and bi-distilled water three times and then is centrifuged. At the end, the final solid is dried in an oven.

Characterization

The crystal structure of ZnO NPs is analyzed by a powder X-ray diffractometer (XRD) advanced Bruker D8 equipped with a source of X-ray. The UV–Vis absorption spectra are recorded using (Shimadzu UV 2450) UV–Vis. spectrophotometer. The photoluminescence (PL) spectra are recorded at room temperature using Fluorescence Spectrophotometer LS 50B, Perkin Elmer. Fourier transform infrared (FTIR) spectra are recorded using Perkin Elmer. The particle size distribution of the powder is measured by photon correlation spectroscopy (PCS), using a Malvern Zetasizer Nano ZS laser particle size analyzer. Raman spectroscopy is studied by a confocal micro-Raman spectrometer ‘LabRam HR 800’ by Horiba Jobin–Yvon, in association with an optical Olympus BX41 microscope.

Results and discussion

X-ray diffraction analysis

All the peaks in the diffractogram have been indexed according to the Hexagonal wurtzite structure of ZnO. As observed in Fig. 1, the main significant peaks are 31.81°, 34.25°, 36.10°, 47.38°, 56.46°, 63.03°, 66.64°, 67.07°, 68.91°, 72.61° and 76.98°. The peaks are indexed as (100), (002), (101), (102), (110), (103), (200), (112), (201), (004) and (202), respectively. These results are consistent with the Committee of Powder Diffraction Standards, JCPDS No. (36-1451). The observed diffractogram shows high and wide peaks, indicating high crystallinity and small size particles. The lattice parameter a and the ratio of the lattice parameters c/a are constant for a given diffraction pattern, so $\frac{\lambda^2}{4a^2}$ is constant for a Hexagonal structural pattern, that can be indexed considering $\frac{4}{3}(h^2 + hk + k^2)$ and $\frac{l^2}{c^2}$ terms in the next equation

$$\sin^2 \theta = \frac{\lambda^2}{4a^2} \frac{4}{3} (h^2 + hk + k^2) + \frac{l^2}{c^2} \quad (1)$$

The summations of the two terms for permissible (hkl) planes are arranged in their ascending order as presented in Table 1. We estimate the lattice parameters $a = b$ and c , and crystallographic axes with angles $\alpha = \beta = 90^\circ$, $\gamma = 120^\circ$. Here, a and c are calculated as following [18, 19]

$$a = \frac{\lambda}{\sqrt{3} \sin \theta} \left(\sqrt{h^2 + hk + k^2} \right) \quad (2)$$

$$c = \frac{\lambda}{2 \sin \theta} l \quad (3)$$

The results are summarized in Table 2, where the average values of the calculated lattice constants are

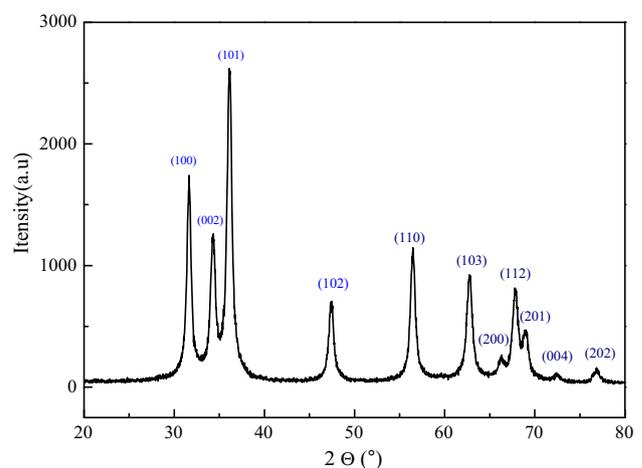


Fig. 1 The X-ray diffraction pattern of ZnO nanoparticles

Table 1 Miller indices (*hkl*) planes for ZnO NPs

<i>h</i>	<i>k</i>	<i>l</i>	$\frac{4}{3}(h^2 + hk + k^2) + \frac{l^2}{3}$
1	0	0	1.333
0	0	2	1.5489
1	0	1	1.7205
1	0	2	2.8819
1	1	0	4
1	0	3	4.8184
2	0	0	5.333
1	1	2	5.5489
2	1	1	5.7205
0	0	4	6.1958
2	0	2	6.8822

Table 2 Values of lattice parameters

2θ	θ	<i>d</i> (Å)	<i>hkl</i>	$h^2 + hk + k^2$	l^2	<i>a</i> (Å)	<i>c</i> (Å)
31.81	15.905	2.8108	100	1	0	3.2457	
34.25	17.12	2.616	002	0	4		5.2322
36.10	18.05	2.4865	101	1	1		
47.38	23.69	1.9172	102	1	4		
56.46	28.23	1.6285	110	3	0	3.2571	
63.03	31.51	1.474	103	1	9		
66.64	33.32	1.4023	200	4	0	3.2385	
68.07	34.034	1.3762	112	3	4		
68.91	34.45	1.3616	201	4	1		
72.61	36.305	1.3001	004	0	16		5.2039
76.98	38.49	1.2376	202	4	4		

$a = 3.24709 \text{ \AA}$ and $c = 5.21807 \text{ \AA}$. The average size of the ZnO nanocrystals is determined using the Debye–Scherrer formula [20, 21]

$$\tau = \frac{k\lambda}{\beta \cos \theta_\beta} \tag{4}$$

where τ presents the particle size diameter in nanometer. k is a constant depending on the shape of the particles and is equal to 0.89. λ , β and θ_β are the wavelength of CuK_α radiation, the full width at half maxima (FWHM) and the Bragg diffraction angle in radian, respectively. The data of crystal size are illustrated in Table 3. The nanocrystals ZnO size of the sample are found to be 10.6 nm, which is derived from the FWHM of the most intense peak corresponding to (101) plane located at 36.094°. In addition, other wurtzite lattice parameters such as the interplanar angle and the unit cell volume could also be considered through Lattice Geometry [21], given by Eqs. 5 and 6 as follows:

Table 3 The crystal size using the Debye–Scherrer relation

2θ	<i>hkl</i>	β (rad)	τ (nm)
31.81	100	0.0165	8.3
34.25	002	0.0204	5.6
36.10	101	0.0129	10.6
47.38	102	0.0126	10.8
56.46	110	0.0131	10.5
63.03	103	0.0215	6.4
66.64	200	0.0441	3.1
68.07	112	0.0191	7.2
68.91	201	0.0093	14.7
72.61	004	0.00005	2.7
76.98	202	0.0088	15.5

$$\cos \varphi = \frac{\left(h_1 h_2 + k_1 k_2 + \frac{1}{2}(h_1 k_2 + h_2 k_1) + \frac{3a^2}{4c^2} l_1 l_2\right)}{\sqrt{\left(h_1^2 + k_1^2 + h_1 k_1 + \frac{3a^2}{4c^2} l_1^2\right)\left(h_2^2 + k_2^2 + h_2 k_2 + \frac{3a^2}{4c^2} l_2^2\right)}} \tag{5}$$

$$V = \frac{\sqrt{3}}{2} a^2 c = 0.866 a^2 c \tag{6}$$

Using Eq. 6 [22], the unit cell volume for the prepared ZnO nanocrystals is estimated to be 47.65 nm³. In addition, from Eq. 5, the interplanar angle between (112) and (201) planes φ is found to be 32° [23].

Size and strain plot

A better evaluation of the size and strain parameters can be obtained by considering an average size and strain plot (SSP) [23]. In this approximation, it is assumed that the crystallite size and the strain profiles are described by a Lorentzian and a Gaussian functions, respectively [24]. Moreover, the peak broadening due to the lattice strain is estimated from the following equation [25]

$$\left(\beta_{hkl} d_{hkl} \cos \theta\right)^2 = \frac{k}{D} \left(d_{hkl}^2 \beta_{hkl} \cos \theta\right) + \left(\frac{\varepsilon}{2}\right)^2 \tag{7}$$

where k is a constant that depends on the shape of the nanoparticles and D is the crystalline size. The term $\left(\beta_{hkl} d_{hkl} \cos \theta\right)^2$ is plotted versus $\left(d_{hkl}^2 \beta_{hkl} \cos \theta\right)$ in Fig. 2. The crystalline size is evaluated from the slope of the linearly fitted data and y-intercept gives the strain ε .

Uniform deformation model

The strain-induced broadening in the nanoparticles due to the crystal imperfection and distortion is calculated using the formula [25]

$$\varepsilon = \frac{\beta_{hkl}}{4 \tan \theta} \tag{8}$$

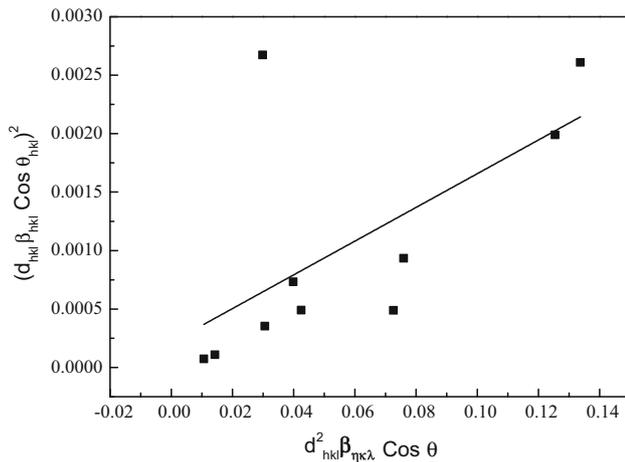


Fig. 2 Average size and strain plot (SSP)

Furthermore, the total broadening is obtained from [26]

$$\beta_{hkl} = \beta_s + \beta_D \quad (9)$$

where β_D is the peak broadening corresponding to crystallite size, β_s is due to strain-induced broadening. β_{hkl} is the width of the half-maximum intensity of instrumental corrected broadening. In addition, W&H analysis are simplified methods, which clearly differentiate between size-induced and strain-induced peak broadening by considering the peak width as a function of 2θ . The instrumental corrected broadening of each diffraction peak is calculated using Eq. 9. From the equation of Debye–Scherrer, it is confirmed that the peak width of the crystallite size varies as $1/\cos\theta$, while the strain varies as $\tan\theta$ in the W&H method [27]

$$\beta_{hkl} = \frac{k\lambda}{D\beta_{hkl}} + 4\varepsilon \tan\theta \quad (10)$$

By rearranging the above equation, we find

$$\beta_{hkl} \cos\theta = \frac{k\lambda}{D} + 4\varepsilon \sin\theta \quad (11)$$

The plot of $\beta_{hkl} \cos\theta$ versus $4 \sin\theta$ for as-prepared ZnO NPs is shown in Fig. 3. From the linear fit, the crystallite size is calculated from the y-intercept and the strain ε is estimated from the slope of the line plotted. The strain takes negative value or compressive strain, which is most likely due to the lattice shrinkage and we suppose that is related to quantum confinement.

Uniform stress deformation model

Uniform deformation stress is taken into the anisotropic nature of Young's modulus of the crystal. The generalized Hooke's law refers to the strain. By assuming a small strain in ZnO crystals, so Hooke's law can be applied here. The

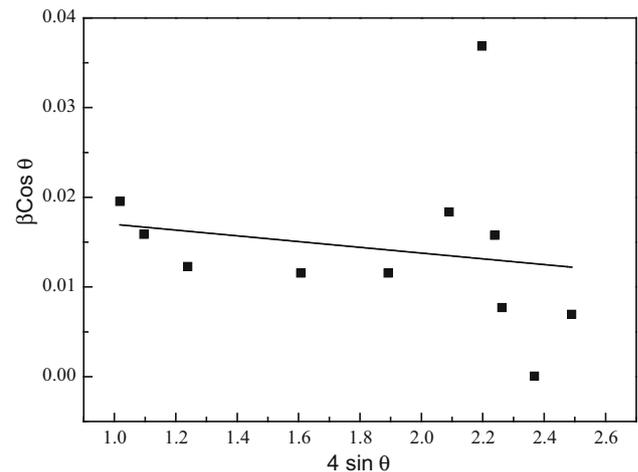


Fig. 3 The W&H analysis of ZnO NPs using UDM

value of σ is determined from the slope of the graph plotted between $\beta_{hkl} \cos\theta$ versus $\frac{4 \sin\theta}{Y_{hkl}}$, represented in Eq. 12. In the USDM, the W&H equation is simply modified by replacing the value of ε in the second term of Eq. 12, where

$$\beta_{hkl} \cos\theta = \frac{k\lambda}{D} + \frac{4\sigma \sin\theta}{Y_{hkl}} \quad (12)$$

By the linear fit of the data, the crystallite size and the strain are determined from the slope and the intercept, respectively, in Fig. 4. All the results obtained from the Scherrer method, W&H models (UDM, USDM) and SSP analyses are summarized in Table 4. Hence, while considering the crystallite size, the strain must be taken into account as in the W&H methods. But when the strain takes negative values the size decreases. By virtue on Hooke's law, a linear proportionality between the stress and strain is given as $\sigma = Y\varepsilon$, where σ is the stress of the crystal and Y is the Young's modulus. For a Hexagonal crystal, Young's modulus is given by the following relation

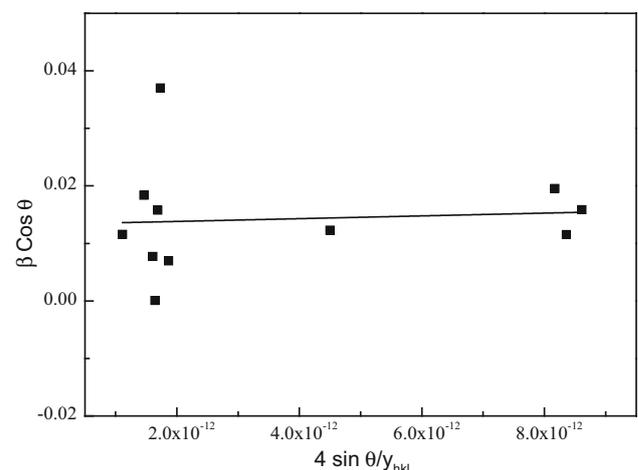


Fig. 4 The W&H analysis of ZnO NPs using USDM

$$Y_{hkl} = \frac{\left(h^2 + \frac{(h+2k)^2}{3} + \left(\frac{al}{c}\right)^2\right)^2}{S_{11}\left(h^2 + \frac{(h+2k)^2}{3}\right)^2 + S_{33}\left(\frac{al}{c}\right)^4 + (2S_{13} + S_{44})\left(h^2 + \frac{(h+2k)^2}{3} + \left(\frac{al}{c}\right)^2\right)^2} \quad (13)$$

Young's modulus Y_{hkl} is related to their elastic compliances S_{ij} [23, 27] where $S_{ij} = S_{11}, S_{13}, S_{33}, S_{44}$ are the elastic compliances of ZnO, with the values of 7.858×10^{-12} , -2.206×10^{-12} , 6.940×10^{-12} , $23.57 \times 10^{-12} \text{ m}^2 \text{ N}^{-1}$, respectively. The estimated Young's modulus of ZnO NPs is equal to 142 GPa, which is significantly larger than the bulk value [27–31]. Chen et al. [32] have reported an experimental measurement of the size-dependent of ZnO nanowires. They found that when the diameter of the nanoparticles is smaller than 120 nm, Young's modulus increases significantly with decreasing diameter. Our result agrees with the experimental trend (Table 4).

Dislocation density and Zn–O bond length

A dislocation is a crystallographic defect or irregularity within a crystal structure. The dislocation density symbolized by δ represents the amount of defects in the powder [21], which is determined from the following equation

$$\delta = \frac{1}{\tau^2} \quad (14)$$

where τ is the particle size, in our case is found to be equal to 8.68 nm, calculated from Debye–Scherrer method. The Zn–O bond length l is given by

$$l = \sqrt{\frac{a^2}{3} + \left(\frac{1}{2} - u\right)^2 c^2} \quad (15)$$

where u is given by

$$u = \frac{a^2}{3c^2} + 0.25 \quad (16)$$

Table 4 Summary of all models results

	Size (nm)	$\varepsilon \times 10^{-3}$	δ (MPa)
Debye–Scherrer	8.6		
SSP	5.2	7.34	
W&H			
UDM	6.8	– 3.2	241
USDM	10.3	17	

The estimated bond length of Zn–O NPs is 1.978 Å, and the dislocation density is about $1.32 \times 10^{16} \text{ m}^{-2}$, while the reported bond length is in the range of 1.87–2.01 Å, which reveals the quantum size of the NPs. The structure seems to be a Hexagonal 3D ZnO chains to form spherical nanoparticles.

Laser light scattering size analyzer

The Malvern Zetasizer is used to measure the particle size in the colloidal solution of ZnO NPs dispersed in ethanol. Even that the ZnO NPs are stored in ambient environment for 14 days, the size distribution remains in narrow range as shown in Fig. 5. The comparison of the results obtained from XRD and DSL methods shows smaller average particle size of about 6 nm, confirming the quantum dot properties.

Fourier Transform infrared spectroscopy

The spectrum in Fig. 6 shows a broad band at 3476 cm^{-1} , assigned to the O–H stretching mode. It is shifted toward low wavenumber that demonstrates the formation of hydrogen bond between the PEG particles and ZnO NPs on their surfaces [33, 34]. The peak at 1100 cm^{-1} is due to C–O(H) vibration that could qualify the coating PEG [35]. The small bands at 2838 and 2900 cm^{-1} are due to C–H stretching vibration of the alkane groups of PTMS and PEG [33, 36]. As it can be seen, the peaks centered at 840 and 890 cm^{-1} are appropriate to Zn–O–Si bonds and Si–O–Si bridges that are formed by in situ self-condensation of the hydrolyzed organosilane molecules [36]. Furthermore, a broad absorption peak at 1000 cm^{-1} is assigned to Si–O vibration as obtained by M. K. Patra et al. [35]. The peak in the region extending from 1250 to 1450 cm^{-1} is likely due to the bending modes of O–H. In addition, the characteristic band for Zn–O stretching vibrations is shifted to a lower wavenumber of 447 cm^{-1} , that is may be due to the presence of silica –Si–O–Si– network on the ZnO NPs [37]. There are two peaks at approximately 1587 and 1413 cm^{-1} correspond to the asymmetric and symmetric stretching vibrations of C=O and C–O in the acetate (COO) groups, respectively [38].



Ultraviolet-visible studies

Figure 7 depicts the absorption spectrum of ZnO in fresh ethanolic colloids. The UV-Vis. spectrum shows a band between 250 and 340 nm, with two maxima at 300 nm and 273 nm, attributed to exciton transitions in small ZnO clusters. As stated in previous reports [39–41], five pronounced absorption features are typically detected, situated near 210, 230, 270, 320 and 360 nm. These electronic transitions reflect the appearance of preferentially stable “magic sizes” from the II–VI-semiconductor cluster chemistry. Furthermore, Searson et al. [42] have analyzed the progressive spectral between 300 and 360 nm which is associated with nanoparticle size range between 2 and 6 nm.

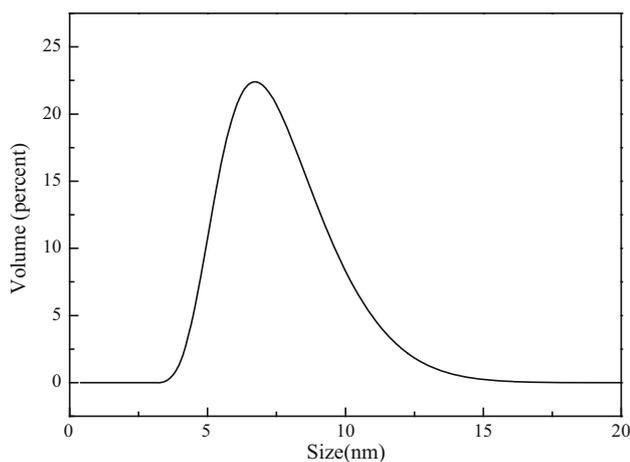


Fig. 5 Particle size distribution of prepared ZnO NPs

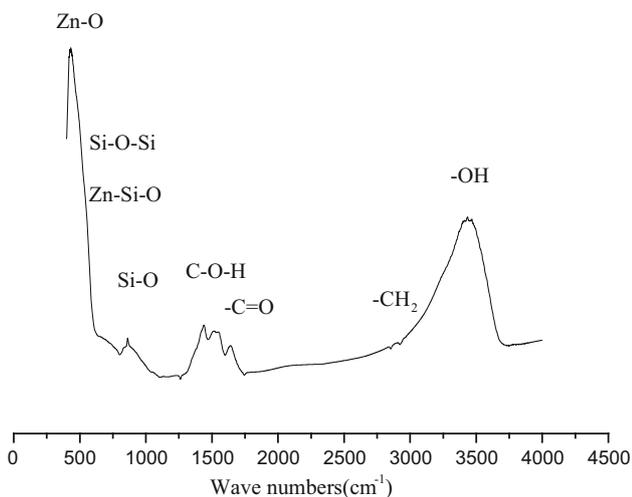


Fig. 6 FTIR full range spectrum of ZnO NPs synthesized

Photoluminescence

In pure ZnO NPs spectrum, the emission broad peak from 400 to 620 nm (blue emission) has been observed in Fig. 8, that is appropriate to surface defect in ZnO [43, 44]. It is inferred that the silane surface modification during the growth process could greatly reduce the aggregation and thus increase the effective surface luminescence [45]. It is recognized that the distinct emission peak in the blue band within 490 nm that is appropriate to the direct recombination of conduction electron in the conduction band and a hole, which may occur from the transition due to oxygen anti-site vacancy defect state [46].

Raman spectroscopy

To further investigate the optical properties, in Fig. 9, we present a typical non-resonant Raman scattering spectrum

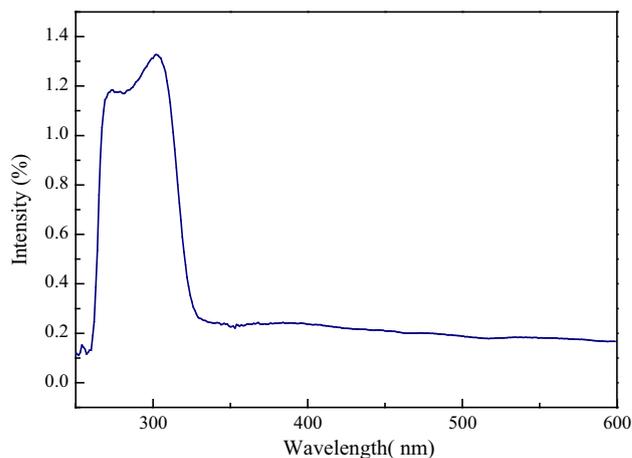


Fig. 7 Optical density of solution colloidal of ZnO NPs synthesized

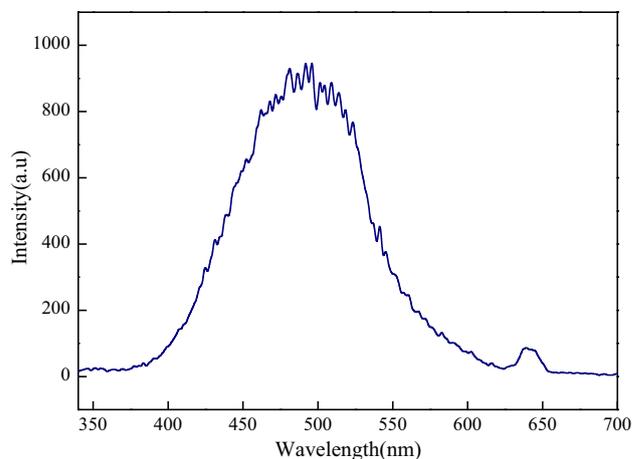


Fig. 8 Luminescence properties of ZnO nanoparticles



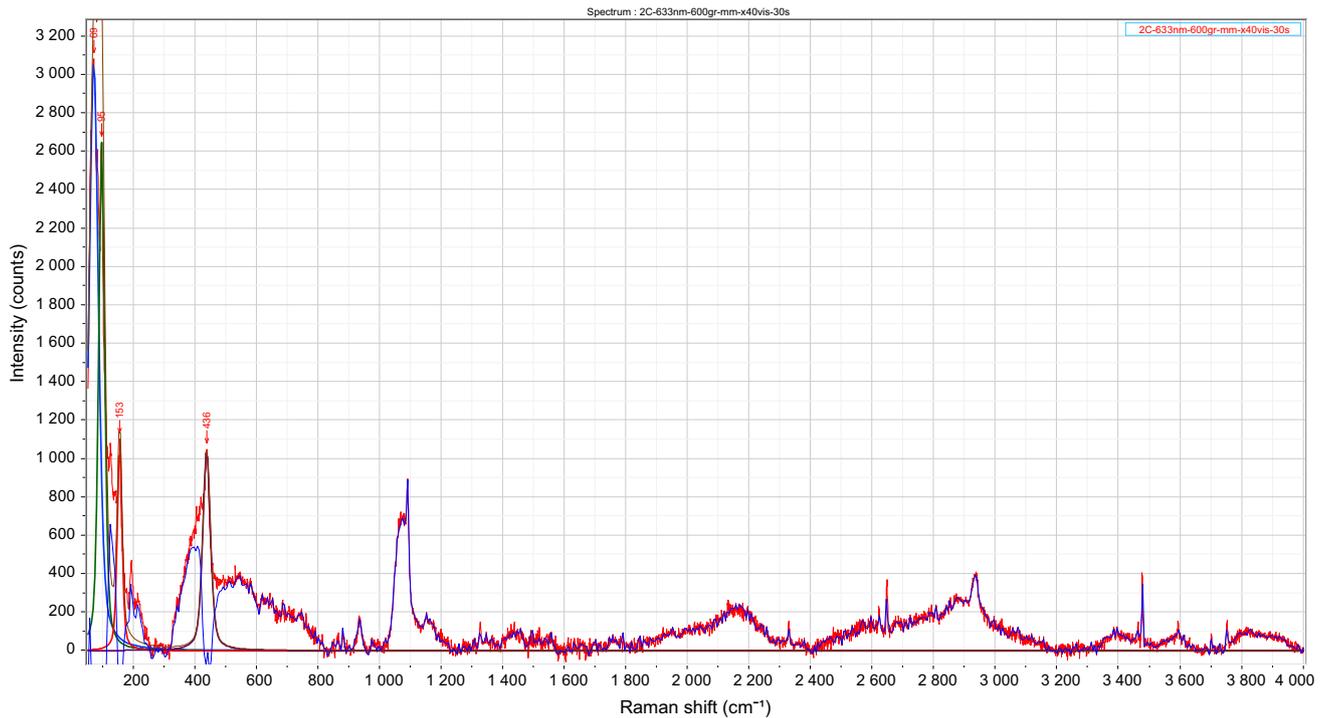


Fig. 9 Raman spectra excited by 633 nm line of as-grown ZnO at room temperature (the blue line is the fitting curve)

Table 5 Raman active phonon mode frequencies (in cm^{-1}) for bulk ZnO and ZnO nanoparticles synthesized

	$E_2(\text{low})$	$A_1(\text{TO})$	$E_1(\text{TO})$	$E_2(\text{high})$	$A_1(\text{LO})$	$E_1(\text{LO})$
ZnO bulk ^a	102	379	410	439	574	591
ZnO NPs	96	380	410	436	580	581

^aRef. [48]

of ZnO NPs obtained under the 633 nm excitation at room temperature. The phonon peaks observed in bulk ZnO and our ZnO NPs cases are summarized in Table 5. A Levenberg–Marquardt nonlinear iteration fitting is performed. The dominating modes in Raman spectrum are $E_2(\text{low})$ at 96 cm^{-1} and $E_2(\text{high})$ at 436 cm^{-1} with $\text{FWHM} = 29 \text{ cm}^{-1}$. The $E_2(\text{high})$ modes are attributed to ZnO non-polar optical phonon, indicating that the sample has a perfect crystal quality [47]. The shift in the position of the $E_2(\text{high})$ phonon mode from the bulk may be attributed to the compressive stress in the ZnO NPs. The origin of this red-shift can be ascribed to optical phonon confinement effects [48, 49]. A band displays as a shoulder at about 410 cm^{-1} , that is qualified to the $E_1(\text{TO})$ mode. The broad peaks at about 380 and 581 cm^{-1} are attributed to $A_1(\text{TO})$ and $E_1(\text{LO})$ modes, respectively, which are associated with oxygen deficiency. Additional Raman modes are observed at 650 cm^{-1} and 935 cm^{-1} . These peaks originate from acetate groups present in reactant traces used in the synthesis and are ascribed to the OCO symmetric bend and C–C symmetric stretch. The peak at

276 cm^{-1} is related to the B_{2s} order mode with low intensity. The broad feature between 1100 and 1200 cm^{-1} is assigned to the two phonon modes (2LO), characteristic of II–IV semiconductors [8, 50].

Conclusion

The zinc oxide nanostructure is successfully synthesized by using sol–gel method with hexagonal wurtzite structure in nanosize range. The synthesized ZnO NPs obtained exhibit a good crystallinity and small size. Scherrer’s formula, W&H (UDM-USDM) and SSP analysis are helpful to determine the size, the stress and the strain with some approximations. UDM and SSP are highly inter-correlated and confirm the small size of our ZnO NPs. The strain is assumed to be uniform in all crystallographic directions, thus considering the isotropic nature of the crystal. Furthermore, the photoluminescence (PL) characterization of the ZnO nanostructures exhibits a broad blue emission in the UV range with maximum peak at 490 nm , which is

attributed to the presence of oxygen anti-site vacancy defect. The size of the ZnO NPs determined by DSL is the about 6 nm. In addition, in Raman spectroscopy, the peak at 436 cm^{-1} corresponds to $E_2(\text{high})$, shifted by 3 cm^{-1} compared to bulk, that is appropriate to the quantum confinement effect. As a result, the surfactant and the capping agent have an effect on the size, the crystallinity and the luminescence of ZnO NPs.

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